

## **MACHAKOS UNIVERSITY**

**University Examinations for 2020/2021 Academic Year** 

# SCHOOL OF ENGINEERING AND TECHNOLOGY DEPARTMENT OF ELECTRICAL AND ELECTRONICS ENGINEERING

### FIRST YEAR FIRST TERM EXAMINATION FOR

## CERTIFICATE IN INFORMATION COMMUNICATION TECHNOLOGY 1602/102 ELECTRICAL PRINCIPLES I

DATE: 3/6/2021 TIME: 11.30-2.30 PM

#### **INSTRUCTIONS**

## Answer all the questions

1 a) State ohms law and give the formula

(2 marks)

- b) Draw the structure of
  - i. Silicon
  - ii. Chlorine

iii.

(6 marks)

- c) Explain the following terms as applied in conductors
  - i. Atomic structure

Boron atoms

ii. Valence (6 marks)

Two resistors each of R $\Omega$  are connected in parallel. Show that their effective equivalent resistance is R/2  $\Omega$  (6 marks)

- 2. a) i Find the conductance of a conductor of resistance of  $5K\Omega$  (4 marks)
  - ii Two  $40\Omega$  resistors are connected in parallel. The combination is then connected in series to a cell of 50V. If the cell has internal resistance of 5  $\Omega$ , calculate,
    - I. The total current flowing
    - II. The energy consumed by one resistor in 30 minutes 55 seconds by one resistor (6 marks)

- b) i Explain what doping means in electronics (4 marks)
  - ii Explain how N-type semiconductor material is achieved (6 marks)
- 3. a) Define, and give an example, a semi-conductor (2 marks)
  - b) Explain what is meant by the following in electronics
    - i. Negative temperature coefficient
    - ii. Trivalent material
    - iii. Doping
    - iv. P-N junction
    - v. Depletion region (10 marks)
  - c) Explain two reasons responsible for reverse bias breakdown (8 marks)
- 4. a) In the circuit given below Calculate
  - i. the current flowing
  - ii. the power dissipated in one of the resistors. (10 marks)

